

L Number	Hits	Search Text	DB	Time stamp
1	17	(silicon or Si) same (Ge or germanium) same (C or carbon) same (etch\$3 stop\$3)	EPO	2003/05/30 15:31
2	0	9615550.URPN.	USPAT	2003/05/30 15:28
3	0	(GeSi SiGe (Si?sub.\$3 near1 Ge?sub.\$3)) near15 (C or carbon) and (etch\$3 stop\$3)	EPO	2003/05/30 15:31
4	8	(GeSi SiGe (Si?sub.\$3 near1 Ge?sub.\$3)) near15 (C or carbon)	EPO	2003/05/30 15:30
5	720	(silicon or Si) same (Ge or germanium) same (C or carbon) same (etch\$3 stop\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:32
12	412	(GeSi SiGe (Si?sub.\$3 near1 Ge?sub.\$3)) near15 (C or carbon) and (etch\$3 stop\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 15:35
19	272	((silicon or Si) same (Ge or germanium) same (C or carbon) same (etch\$3 stop\$3)) and @ad<19941110	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:33
26	79	((silicon or Si) same (Ge or germanium) same (C or carbon) same (etch\$3 stop\$3)) and @rlad<19941110	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 15:36
33	289	((silicon or Si) same (Ge or germanium) same (C or carbon) same (etch\$3 stop\$3)) and @ad<19941110) ((silicon or Si) same (Ge or germanium) same (C or carbon) same (etch\$3 stop\$3)) and @rlad<19941110)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 15:37
40	6	5273829.URPN.	USPAT	2003/05/30 17:15
41	8	("4393127" "4495262" "4656110" "4698287" "4778692" "4855197" "4885226" "5049640").PN.	USPAT	2003/05/30 17:22
42	71	5013681.URPN.	USPAT	2003/05/30 17:40
43	0	6559058.URPN.	USPAT	2003/05/30 17:38
44	1304	SiGeC GeSiC (silicon near1 germanium near2 (carbide carbon))	USPAT	2003/05/30 17:42
45	2244	SiGeC GeSiC (silicon near1 germanium near2 (carbide carbon))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:40
52	2	5013681.URPN. and (SiGeC GeSiC (silicon near1 germanium near2 (carbide carbon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 17:42
59	1		USPAT	2003/05/30 17:44
60	19	5024723.URPN.	USPAT	2003/05/30 17:45
61	1		USPAT	2003/05/30 18:30
62	284	(silicon or Si) same (Ge or germanium) same (carbide or carbon) same (etch\$3 stop\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:33
69	86	((silicon or Si) same (Ge or germanium) same (carbide or carbon) same (etch\$3 stop\$3)) and @ad<19941110	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:34
76	31	((silicon or Si) same (Ge or germanium) same (carbide or carbon) same (etch\$3 stop\$3)) and @rlad<19941110	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:36

83	28	(SiGeC GeSiC (silicon near1 germanium near2 (carbide carbon))) near15 (etch\$3 stop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/30 18:40
----	----	---	---	------------------